Diode Semiconductor Device - Page 1 of 1



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Ir	nclosure Material:
G	ilass
0	overall Length:
0	.240 inches
0	overall Diameter:
0	.128 inches
N	Iounting Method:
Т	erminal
F	eatures Provided:
Н	lermetically sealed case
S	emiconductor Material:
S	ilicon
v	oltage Rating In Volts Per Characteristic:
2	00.0 reverse voltage, peak
С	current Rating Per Characteristic:
1	0.00 microamperes forward current, average major
Т	erminal Type And Quantity:
2	uninsulated wire lead
S	helf Life:
Ν	l/a
U	Init Of Measure:
D	emilitarization:
Ν	lo
F	iig:
A	110a0